

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
1	BRS	L1	1675	257/786.ccls.	US-PGPU B; USPAT; USOCR	2006/05/27 19:21	
2	BRS	L2	2081	257/773.ccls.	US-PGPU B; USPAT; USOCR	2006/05/27 19:20	
3	BRS	L3	1090	257/48.ccls.	US-PGPU B; USPAT; USOCR	2006/05/27 19:20	
4	BRS	L4	2007	257/737.ccls.	US-PGPU B; USPAT; USOCR	2006/05/27 19:20	
5	BRS	L5	356	257/786.ccls.	EPO; JPO; DER WENT; IBM_TDB	2006/05/27 19:21	

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments
6	BRS	L6	449	257/773.ccls.	EPO; JPO; DER WEN T; IBM_ TDB	2006/05/27 19:21	
7	BRS	L7	335	257/48.ccls.	EPO; JPO; DER WEN T; IBM_ TDB	2006/05/27 19:21	
8	BRS	L8	13	((chip or silicon or die) and (electrode or pad or terminal) and (bump or ball) and first and second and input and output and (cell or circuit) and (probe or test)).clm.	US- PGPU B	2006/05/27 19:23	